

# LSIC2SD065D06A 650 V, 6 A SiC Schottky Barrier Diode









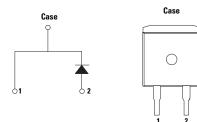
### **Description**

This series of silicon carbide (SiC) Schottky diodes has negligible reverse recovery current, high surge capability, and a maximum operating junction temperature of 175 °C. These diodes series are ideal for applications where improvements in efficiency, reliability, and thermal management are desired.

#### **Features**

- AEC-Q101 qualified
- Positive temperature coefficient for safe operation and ease of paralleling
- 175 °C maximum operating junction temperature
- Excellent surge capability
- Extremely fast, temperature-independent switching behavior
- Dramatically reduced switching losses compared to Si bipolar diodes

## Circuit Diagram TO-263-2L



#### **Applications**

- Boost diodes in PFC or DC/DC stages
- Switch-mode power supplies
- Uninterruptible power supplies
- · Solar inverters
- Industrial motor drives
- EV charging stations

### **Environmental**

• Littelfuse "RoHS" logo = RoHS conform



• Littelfuse "HF" logo = HF Halogen Free

• Littelfuse "Pb-free" logo = Pb-free lead plating



#### **Maximum Ratings**

Characteristics	Symbol	Conditions	Value	Unit	
Repetitive Peak Reverse Voltage	V <sub>RRM</sub>	-	650	V	
DC Blocking Voltage	V <sub>R</sub>	T <sub>J</sub> = 25 °C	650	V	
Continuous Forward Current		T <sub>c</sub> = 25 °C	18.5	А	
	l <sub>F</sub>	T <sub>C</sub> = 135 °C	8.6		
		T <sub>C</sub> = 152 °C	6		
Non-Repetitive Forward Surge Current	$I_{FSM}$ $T_{C} = 25  ^{\circ}\text{C}, T_{P} = 10  \text{ms},  \text{Half sine pulse}$		32	А	
Power Dissipation	D	$T_{\rm C} = 25  ^{\circ}{\rm C}$	75	W	
	P <sub>Tot</sub>	T <sub>C</sub> = 110 °C	32		
Operating Junction Temperature	T <sub>J</sub>	-	-55 to +175	°C	
Storage Temperature	T <sub>STG</sub>	-	-55 to +150	°C	
Soldering Temperature (reflow MSL 1)	T <sub>SOLD</sub>	-	260	°C	



### Electrical Characteristics (T, =25 °C unless otherwise specified)

	Symbol	Conditions	Value				
Characteristics			Min.	Тур.	Max.	Unit	
Forward Voltage	.,	I <sub>F</sub> = 6 A, T <sub>J</sub> = 25 °C	-	1.5	1.8	V	
	V <sub>F</sub>	I <sub>F</sub> = 6 A, T <sub>J</sub> = 175 °C	-	1.85	-		
Reverse Current	I <sub>R</sub> -	$V_R = 650  V$ , $T_J = 25  ^{\circ}C$	-	<1	50	μΑ	
		$V_{_{\rm R}} = 650  \text{V}$ , $T_{_{\rm J}} = 175  ^{\circ}\text{C}$	-	15	-		
Capacitance	С	$V_R = 1 V$ , $f = 1 MHz$	-	300	-	-	
		V <sub>R</sub> = 200 V, f = 1 MHz	-	39	-	pF	
		$V_R = 400 \text{ V, f} = 1 \text{ MHz}$	-	28	-		
Total Capacitive Charge	Q <sub>c</sub>	$V_R = 400 \text{ V},$ $V_R = \sqrt{\frac{V_R}{Q_C}}$ $Q_C = \int C(V)dV$	-	20	-	nC	

## **Thermal Characteristics**

Characteristics	Symbol	Value	Unit
Thermal Resistance	R <sub>Jc</sub>	2.0	°C/W

Figure 1: Typical Foward Characteristics

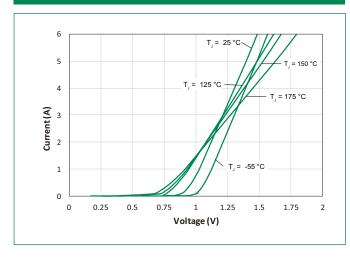


Figure 2: Typical Reverse Characteristics

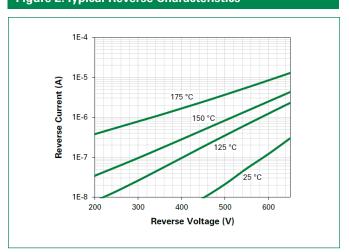




Figure 3: Power Derating

0

25

Figure 4: Current Derating 70 10% Duty 30% Duty 60 50% Duty Forward Current (A) 70% Duty DC 50 40 30 20 10 0 25 50 100 175 125 Case Temperature (°C)

Figure 5: Capacitance vs. Reverse Voltage

50

75

100

Case Temperature (°C)

125

150

175

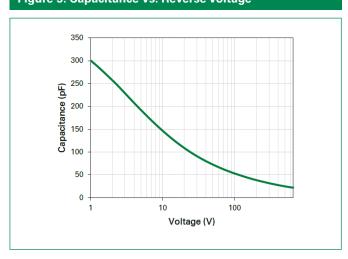


Figure 6: Capacitive Charge vs. Reverse Voltage

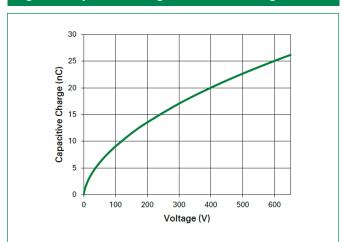


Figure 7: Stored Energy vs. Reverse Voltage

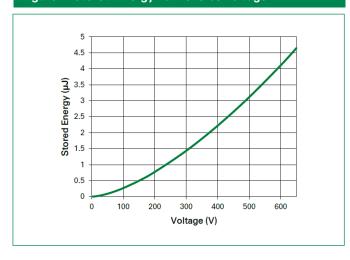
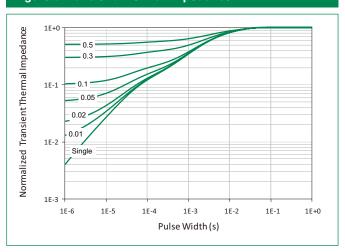
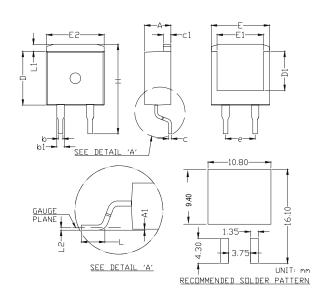


Figure 8: Transient Thermal Impedance

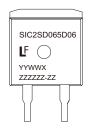


## Dimensions-Package TO-263-2L



Symbol	Millimeters				
Cymbol	Min	Nom	Max		
А	4.30	4.50	4.70		
A1	0.00	-	0.25		
b	0.70	0.80	0.90		
b1	1.17	1.27	1.37		
С	0.46	0.50	0.60		
c1	1.25	1.30	1.40		
D	9.00	9.20	9.40		
D1	6.50	6.70	6.90		
E	9.80	10.00	10.20		
E1	7.80	8.00	8.20		
E2	9.70	9.90	10.10		
е	5.08 BSC				
Н	15.00	15.30	15.60		
L	2.00	2.30	2.60		
L1	1.00	1.20	1.40		
L2	0.254 BSC				

## **Part Numbering and Marking System**



 SIC
 = SiC Diode

 2
 = Gen2

 SD
 = Schottky Diode

 065
 = Voltage Rating (650 V)

 D
 = TO-263 Package (2 Lead)

 06
 = Current Rating (6 A)

 YY
 = Year

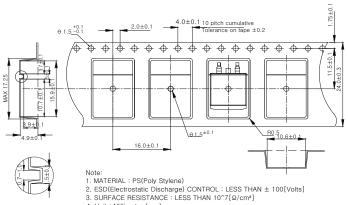
WW = Week
X = Special Code
ZZZZZZ-ZZ = Lot Number

## **Packing Option**

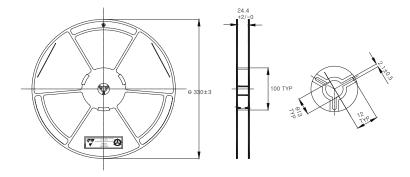
Part Number	Marking	Packing Mode	M.O.Q
LSIC2SD065D06A	SIC2SD065D06	Tape and Reel	800



### **TO-263 Carrier Reel Specifications**



Unit : Millimeter (mm)



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